

205N10LS-VB Datasheet N-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{(BR)DSS} (V)	$r_{DS(on)}(\Omega)$	I _D (A)		
100	0.017 at V _{GS} = 10 V	30		

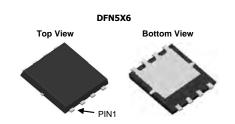
FEATURES

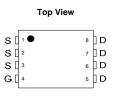
- Trench Power MOSFET
- 175 °C Junction Temperature
- Low Thermal Resistance Package
- 100 % R_g Tested

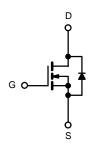


APPLICATIONS

• Isolated DC/DC Converters







N-Channel MOSFET

ABSOLUTE MAXIMUM RATING	iS (T _A = 25 °C, u	nless other	wise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	100	V	
Gate-source voltage		V_{GS}	± 20	v	
	T _C = 25 °C		30		
Continuous drain surrent /T 150 °C)	T _C = 70 °C	1 .	19		
Continuous drain current (T _J = 150 °C)	T _A = 25 °C	l _D	10 ^{b, c}	İ	
	T _A = 70 °C	1	8.5 ^{b, c}		
Pulsed drain current (t = 100 μs)		I _{DM}	75	A	
Continuous source drain diade surrent	T _C = 25 °C	,	56		
Continuous source-drain diode current	T _A = 25 °C	l _S	4.5 b, c	İ	
Single pulse avalanche current L = 0.1 mH		I _{AS}	20		
Single pulse avalanche energy	L = 0.1 IIII	E _{AS}	20	mJ	
	T _C = 25 °C		60	W	
Maximum naurar dissination	T _C = 70 °C	Б	40		
Maximum power dissipation	T _A = 25 °C	P _D	5 b, c		
	T _A = 70 °C		3.2 b, c		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) ^c			260	7	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT	
Maximum junction-to-ambient b	t ≤ 10 s	R _{thJA}	20	25	°C/W	
Maximum junction-to-case (drain)	Steady state	R_{thJC}	1.6	2	C/VV	

Notes

- a. Package limited
- b. Surface mounted on 1" x 1" FR4 board
- c. t = 10 s

服务热线:400-655-8788

1

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100	-	-	V	
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$	$I_D = 10 \text{ mA}$	-	81	-	mV/°C	
V _{GS(th)} temperature coefficient	$\Delta V_{GS(th)}/T_J$	$I_D = 250 \mu A$	-	-7.5	-	IIIV/ C	
Gate-source threshold voltage							

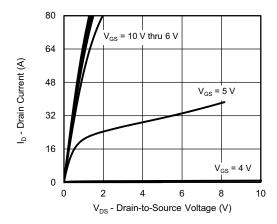
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

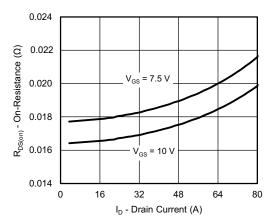
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



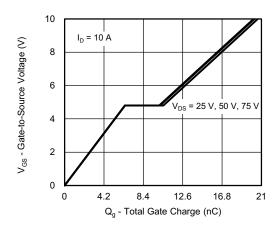
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



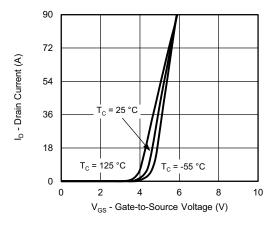
Output Characteristics



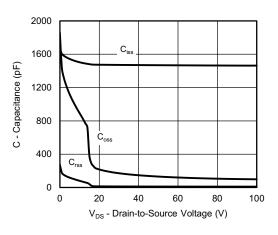
On-Resistance vs. Drain Current and Gate Voltage



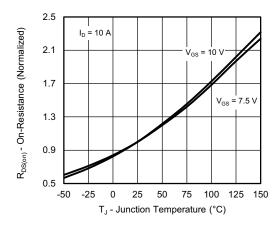
Gate Charge



Transfer Characteristics



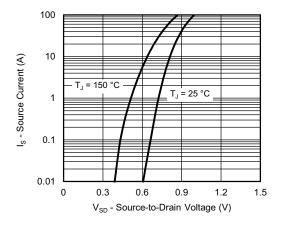
Capacitance



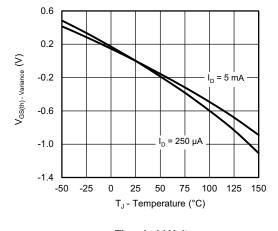
On-Resistance vs. Junction Temperature



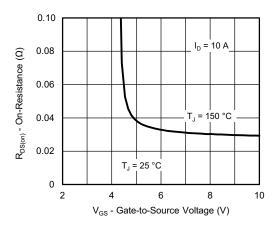
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Source-Drain Diode Forward Voltage

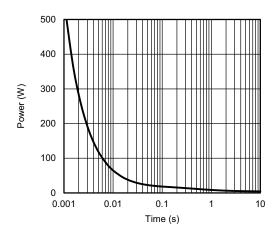


Threshold Voltage

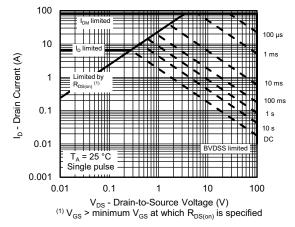


On-Resistance vs. Gate-to-Source Voltage

4



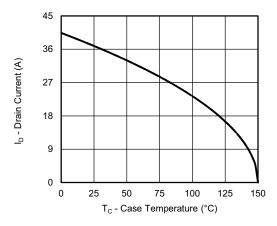
Single Pulse Power, Junction-to-Ambient



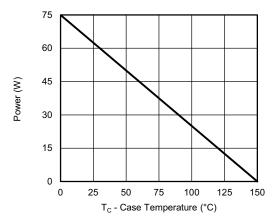
Safe Operating Area, Junction-to-Ambient



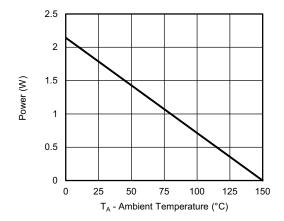
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating ^a







Power, Junction-to-Ambient

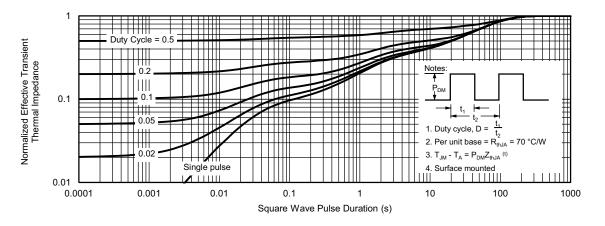
Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

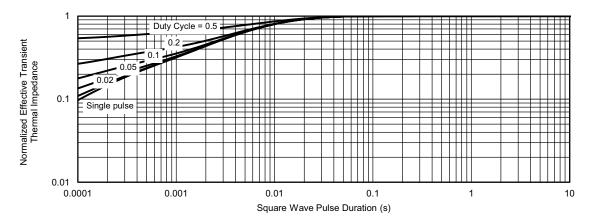
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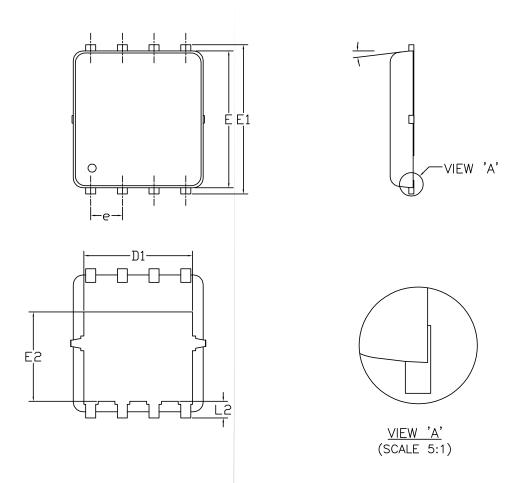
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

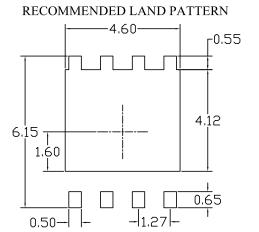


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case





	-					
C			•	DIMENSIONS IN INCHES		
S		NOM	MAX	MIN	NOM	MAX
A	0.85	0. 95	1.00	0.033	0.037	0.039
	0.00		0.05	0.000		0.002
	0.30		0.50	0.012	0.016	0.020
c	0.15	0. 20	0. 25	0.006	0.008	0.010
					0. 205	
D1		4. 35			0.171	
		5. 55			0. 219	
		6.05			0. 238	
E2		3. 625	_		0.143	
e	1. 27 BSC				0.050 BSC	
L	0.45	0. 55	0.65	0.018	0.022	0.026
L1	0		0.15	0		0.006
L2		0.68 REF			0.027 REF	
	0°		10°	0°		10°

NOTE

- 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS. MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
- 2. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.

UNIT: mm



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